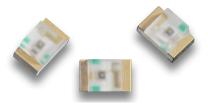


AP2012F3C

2.0 x 1.25 mm Infrared Emitting Diode



DESCRIPTION

• F3 Made with Gallium Arsenide Infrared Emitting diodes

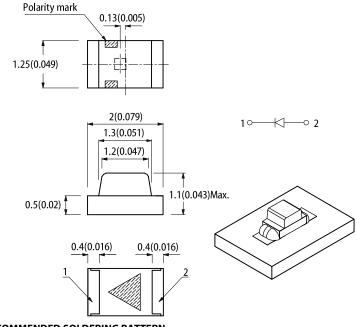
FEATURES

- 2.0 mm x 1.25 mm SMD LED, 1.1 mm thickness
- · Mechanically and spectrally matched to the phototransistor
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- Halogen-free
- RoHS compliant

APPLICATIONS

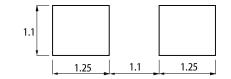
- · Infrared Illumination for cameras
- Machine vision systems
- Surveillance systems
- Industrial electronics
- IR data transmission
- Remote control





RECOMMENDED SOLDERING PATTERN

(units : mm; tolerance : ± 0.1)



Notes

All dimensions are in millimeters (inches).
 Tolerance is ±0.1(0.004") unless otherwise noted.
 The specifications, characteristics and technical data described in the datasheet are subject to

change without prior notice.

The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

Part Number	Emitting Color (Material)	Lens Type	Po (mW/sr) @ 20mA [2]		Viewing Angle ^[1]	
			Min.	Тур.	201/2	
AP2012F3C	Infrared (GaAs)	Water Clear	1.2	3	(00 ⁸	
			*0.8	*2	160°	

Notes

 ^{41/2} is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
 Radiant Intensity / luminous flux: +/-15%.
 * Radiant intensity value is traceable to CIE127-2007 standards.

Kingbright

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Devenator	Cumula al	Emitting Color	Value		l la it
Parameter	Symbol	Emitting Color	Typ. Max.	Max.	Unit
Wavelength at Peak Emission I_F = 20mA	λ_{peak}	Infrared	940	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 20mA	Δλ	Infrared	50	-	nm
Capacitance	С	Infrared	90	-	pF
Forward Voltage I_F = 20mA	V _F ^[1]	Infrared	1.2	1.6	V
Reverse Current (V _R = 5V)	I _R	Infrared	-	10	μΑ
Temperature Coefficient of Wavelength I_F = 20mA, -10°C \leq T \leq 85°C	TC _λ	Infrared	0.3	-	nm/°C
Temperature Coefficient of $~V_F$ I_F = 20mA, -10 $^{\circ}C \leq T \leq 85 ^{\circ}C$	TCv	Infrared	-1.2	-	mV/°C

Notes:

Forward voltage: ±0.1V.
 Wavelength value is traceable to CIE127-2007 standards.
 Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

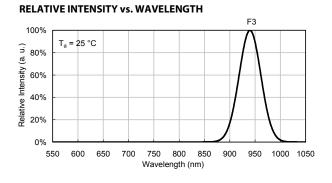
Parameter	Symbol	Value	Unit
Power Dissipation	P _D	90	mW
Reverse Voltage	V _R	5	V
Junction Temperature	Tj	115	°C
Operating Temperature	T _{op}	-40 to +85	°C
Storage Temperature	T _{stg}	-40 to +85	°C
DC Forward Current	l _F	50	mA
Peak Forward Current	I _{FM} ^[1]	1200	mA
Electrostatic Discharge Threshold (HBM)	-	8000	V
Thermal Resistance (Junction / Ambient)	R _{th JA} ^[2]	440	°C/W
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[2]	290	°C/W

ABSOLUTE MAXIMUM RATINGS at T_A=25°C

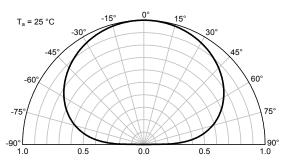
Notes: 1. 1/100 Duty Cycle, 10µs Pulse Width. 2. R_{th. JA}, R_{th. JS} Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad). 3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

Kingbright

TECHNICAL DATA

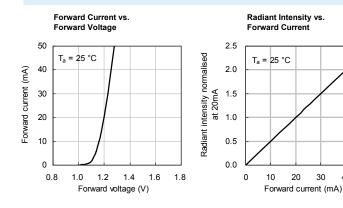


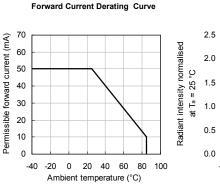
SPATIAL DISTRIBUTION



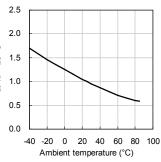
INFRARED

40 50

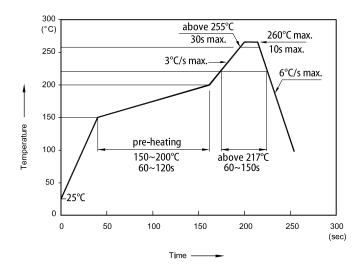




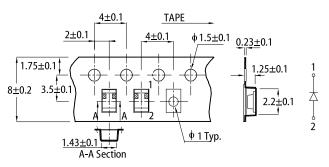
Radiant Intensity vs. Ambient Temperature



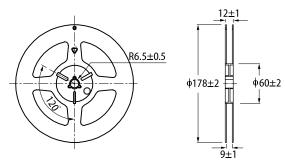
REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS



TAPE SPECIFICATIONS (units:mm)



REEL DIMENSION (units:mm)



Notes:

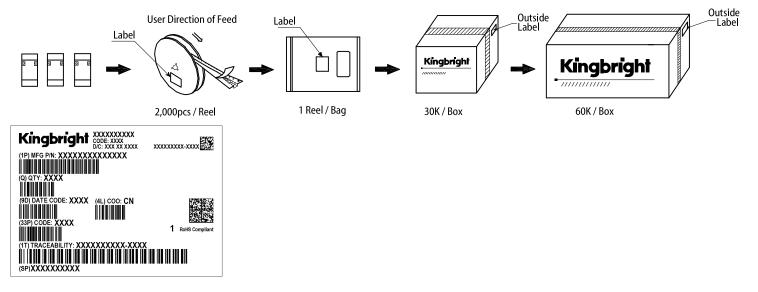
- Don't cause stress to the LEDs while it is exposed to high temperature.
 The maximum number of reflow soldering passes is 2 times.
 Reflow soldering is recommended. Other soldering methods are not recommended as they might

cause damage to the product.

Kingbright

AP2012F3C

PACKING & LABEL SPECIFICATIONS



PRECAUTIONARY NOTES

- The information included in this document reflects representative usage scenarios and is intended for technical reference only.
- The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications. 2.
- When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues. The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening 3.
- 4. The contents and information of this document may not be reproduced or re-transmitted without permission by Kingbright. All design applications should refer to Kingbright application notes available at <u>https://www.KingbrightUSA.com/Application</u>
- 5. 6. onNotes

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Infrared Emitters category:

Click to view products by Kingbright manufacturer:

Other Similar products are found below :

LTE-309 LTE-3279K LTE-4206C LTE-4208C EAILP03RDAA6 LTE-2871C LTE-4238 ASDL-4264-C22 OED-EL305F4C50-HT OP216-004 LTE-3376 EEL109 HL-PST-1608IR1C-L4 SFH 7016 IN-S126ETIR IN-S126DSHIR IN-S126ETHIR IN-P32ZTHIR IN-S42CTQHIR IN-S126BTHIR IN-S63DTHIR IN-S85BTHIR IN-S63FTHIR EAIST3535A1 EAIST3535A4 MHT153IRCT MHS153IRCT HIR204C/H0 HIR323C LTE-209 HSDL-4400#011 IR12-21C/TR8 IR17-21C/TR8 IR26-21C/L110/TR8 IR91-21C/TR10 KM-4457F3C L-53F3BT WP3A10F3C LTE-4208 IR42-21C/TR8 HSDL-4261 APA3010F3C-GX SE2460-140 OP266-905 OP280D LTE-2871 HIR8323/C16 KP-2012SF4C KPA-3010F3C L-7113SF6C